SCBS212D - JUNE 1992 - REVISED JULY 1999

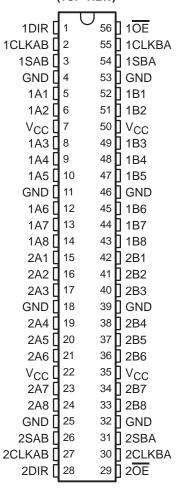
- **Members of the Texas Instruments** Widebus™ Family
- State-of-the-Art *EPIC-IIB™* BiCMOS Design Significantly Reduces Power Dissipation
- Latch-Up Performance Exceeds 500 mA Per **JESD 17**
- Typical V_{OLP} (Output Ground Bounce) < 1 V at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$
- Distributed V_{CC} and GND Pin Configuration **Minimizes High-Speed Switching Noise**
- Flow-Through Architecture Optimizes PCB
- High-Drive Outputs (-32-mA I_{OH}, 64-mA I_{OI})
- **Package Options Include Plastic Shrink** Small-Outline (DL), Thin Shrink Small-Outline (DGG) Packages and 380-mil Fine-Pitch Ceramic Flat (WD) Package Using 25-mil Center-to-Center Spacings

description

The 'ABT16646 devices consist bus-transceiver circuits, D-type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the input bus or from the internal registers.

These devices can be used as two 8-bit transceivers or one 16-bit transceiver. Data on the A or B bus is clocked into the registers on the low-to-high transition of the appropriate clock (CLKAB or CLKBA) input. Figure 1 illustrates the four fundamental bus-management functions that can be performed with the 'ABT16646 devices.

SN54ABT16646 . . . WD PACKAGE SN74ABT16646 . . . DGG OR DL PACKAGE (TOP VIEW)



Output-enable (OE) and direction-control (DIR) inputs are provided to control the transceiver functions. In the transceiver mode, data present at the high-impedance port may be stored in either register or in both. The select-control (SAB and SBA) inputs can multiplex stored and real-time (transparent mode) data. The circuitry used for select control eliminates the typical decoding glitch that occurs in a multiplexer during the transition between stored and real-time data. The direction control (DIR) determines which bus receives data when OE is low. In the isolation mode (OE high), A data can be stored in one register and/or B data can be stored in the other register.

When an output function is disabled, the input function is still enabled and can be used to store and transmit data. Only one of the two buses, A or B, can be driven at a time.

To ensure the high-impedance state during power up or power down, $\overline{\sf OE}$ should be tied to ${\sf V}_{\sf CC}$ through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

Widebus and EPIC-IIB are trademarks of Texas Instruments Incorporated.



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description (continued)

The SN54ABT16646 is characterized for operation over the full military temperature range of -55° C to 125° C. The SN74ABT16646 is characterized for operation from -40° C to 85° C.

FUNCTION TABLE

		INP	UTS			DATA	A 1/0†	OPERATION OR FUNCTION
ŌĒ	DIR	CLKAB	CLKBA	SAB	SBA	A1-A8	B1-B8	OPERATION OR FUNCTION
Х	Х	1	Х	Х	Х	Input	Unspecified	Store A, B unspecified [†]
Х	X	Χ	↑	X	Χ	Unspecified	Input	Store B, A unspecified [†]
Н	Х	1	↑	Х	Χ	Input	Input	Store A and B data
Н	Χ	H or L	H or L	X	Χ	Input disabled	Input disabled	Isolation, hold storage
L	L	Х	Х	Х	L	Output	Input	Real-time B data to A bus
L	L	Χ	H or L	Х	Н	Output	Input	Stored B data to A bus
L	Н	Х	Х	L	Х	Input	Output	Real-time A data to B Bus
L	Н	H or L	Χ	Н	Χ	Input	Output	Stored A data to bus

[†] The data-output functions can be enabled or disabled by various signals at $\overline{\text{OE}}$ or DIR. Data-input functions always are enabled, i.e., data at the bus terminals is stored on every low-to-high transition of the clock inputs.



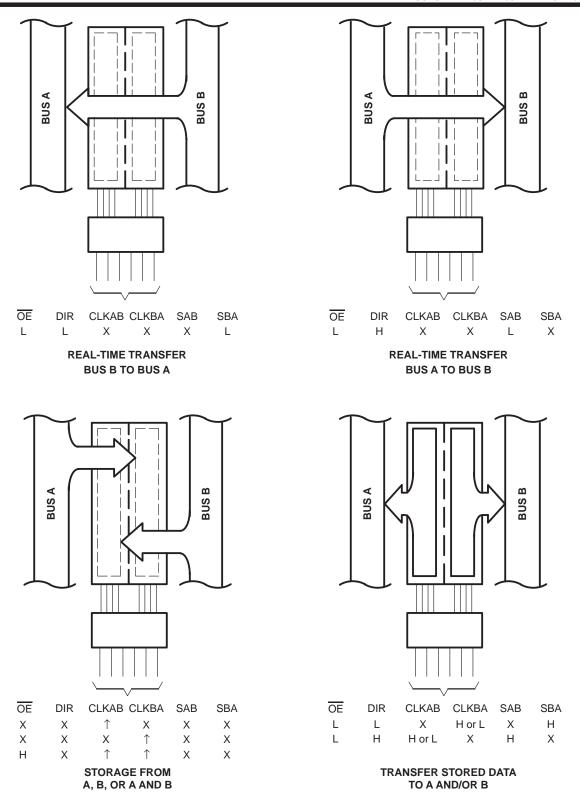
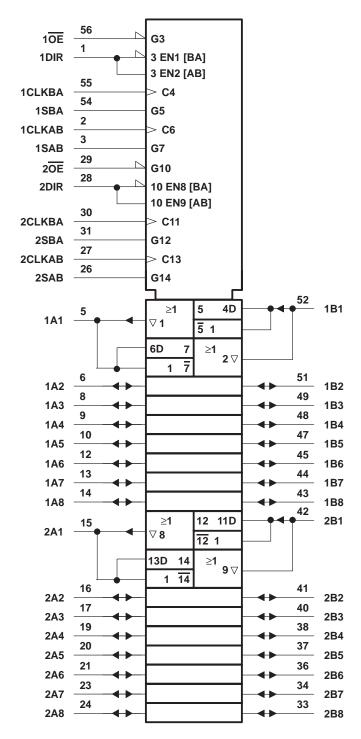


Figure 1. Bus-Management Functions



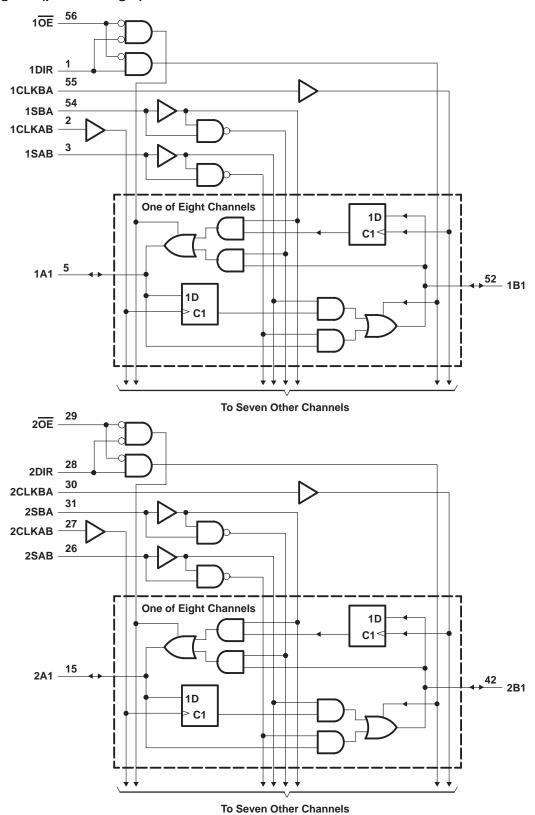
logic symbol[†]



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.



logic diagram (positive logic)





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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage range, V _{CC}	0.5 V to 7 V
Input voltage range, V _I (except I/O ports) (see Note 1)	0.5 V to 7 V
Voltage range applied to any output in the high or power-off state, VO	–0.5 V to 5.5 V
Current into any output in the low state, IO: SN54ABT16646	96 mA
SN74ABT16646	128 mA
Input clamp current, I _{IK} (V _I < 0)	–18 mA
Output clamp current, I _{OK} (V _O < 0)	–50 mA
Package thermal impedance, θ _{JA} (see Note 2): DGG package	81°C/W
DL package	74°C/W
Storage temperature range, T _{stg}	–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions (see Note 3)

			SN54AB1	Г16646	SN74AB1	Г16646	UNIT
			MIN	MAX	MIN	MAX	UNIT
Vcc	Supply voltage		4.5	5.5	4.5	5.5	V
VIH	High-level input voltage		2		2		V
V _{IL}	Low-level input voltage			0.8		0.8	V
٧ _I	Input voltage		0	Vcc	0	Vcc	V
ІОН	High-level output current			-24		-32	mA
loL	Low-level output current			48		64	mA
Δt/Δν	Input transition rise or fall rate	Outputs enabled		10		10	ns/V
TA	Operating free-air temperature		-55	125	-40	85	°C

NOTE 3: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

^{2.} The package thermal impedance is calculated in accordance with JESD 51.

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DAE	RAMETER	TEST COM	DITIONS	Т	A = 25°C	;	SN54AB	Г16646	SN74AB1	16646	UNIT
PAR	KAWETER	TEST CON	DITIONS	MIN	TYP [†]	MAX	MIN	MAX	MIN	MAX	UNII
٧ıK		$V_{CC} = 4.5 \text{ V},$	$I_{I} = -18 \text{ mA}$			-1.2		-1.2		-1.2	V
		V _{CC} = 4.5 V,	$I_{OH} = -3 \text{ mA}$	2.5			2.5		2.5		
\/~··		$V_{CC} = 5 V$,	$I_{OH} = -3 \text{ mA}$	3			3		3		V
VOH		V _{CC} = 4.5 V	$I_{OH} = -24 \text{ mA}$	2			2				v
		VCC = 4.5 V	$I_{OH} = -32 \text{ mA}$	2*					2		
VOL		V _{CC} = 4.5 V	I _{OL} = 48 mA			0.55		0.55			V
VOL		VCC = 4.5 V	I _{OL} = 64 mA			0.55*				0.55	V
V _{hys}					100						mV
I _I	Control inputs	V _{CC} = 5.5 V, V _I = V ₀	CC or GND			±1		±1		±1	μΑ
	A or B ports					±20		±20		±20	
I _{OZH} ‡		$V_{CC} = 5.5 \text{ V},$	$V_0 = 2.7 \text{ V}$			10		10		10	μΑ
lozL [‡]		$V_{CC} = 5.5 \text{ V},$	$V_0 = 0.5 V$			-10		-10		-10	μΑ
I _{off}		$V_{CC} = 0$,	V_I or $V_O \le 4.5 \text{ V}$			±100				±100	μΑ
ICEX		V _{CC} = 5.5 V, V _O = 5.5 V	Outputs high			50		50		50	μА
ΙΟ§		V _{CC} = 5.5 V,	V _O = 2.5 V	-50	-100	-180	-50	-180	-50	-180	mA
		V _{CC} = 5.5 V,	Outputs high			2		2		2	
Icc	A or B ports	$I_0 = 0$,	Outputs low			32		32		32	mA
		$V_I = V_{CC}$ or GND	Outputs disabled			2		2		2	
	Data inputs	V _{CC} = 5.5 V, One input at 3.4 V,	Outputs enabled			50		50		50	
ΔICC¶	Data Inputs	Other inputs at V _{CC} or GND	Outputs disabled			50		50		50	μΑ
	Control inputs	V _{CC} = 5.5 V, One in Other inputs at V _{CC}				50		50		50	
Ci	Control inputs	V _I = 2.5 V or 0.5 V			4						pF
C _{io}	A or B ports	V _O = 2.5 V or 0.5 V			8						pF

^{*} On products compliant to MIL-PRF-38535, this parameter does not apply.

[†] All typical values are at $V_{CC} = 5 \text{ V}$.

[‡]The parameters I_{OZH} and I_{OZL} include the input leakage current.

[§] Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

[¶] This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.

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timing requirements over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 2)

		,	SN54AE	T16646		
		V _{CC} =	= 5 V, 25°C	MIN	MAX	UNIT
		MIN	MAX			
fclock	Clock frequency		125		125	MHz
t _W	Pulse duration, CLK high or low	4.3		4.3		ns
t _{su}	Setup time, A or B before CLKAB↑ or CLKBA↑	3.5		4		ns
t _h	Hold time, A or B after CLKAB↑ or CLKBA↑	0.5		0.5		ns

timing requirements over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 2)

			SN74AE	T16646		
		V _{CC} =	= 5 V, 25°C	MIN	MAX	UNIT
		MIN	MAX			
fclock	Clock frequency		125		125	MHz
t _W	Pulse duration, CLK high or low	4.3		4.3		ns
t _{su}	Setup time, A or B before CLKAB↑ or CLKBA↑	3		3		ns
th	Hold time, A or B after CLKAB↑ or CLKBA↑	0		0		ns



switching characteristics over recommended ranges of supply voltage and operating free-air temperature, C_L = 50 pF (unless otherwise noted) (see Figure 2)

				SN5	4ABT16	646		
PARAMETER	FROM (INPUT)	TO (OUTPUT)		CC = 5 V 4 = 25°C		MIN	MAX	UNIT
				TYP	MAX			
f _{max}			125			125		MHz
t _{PLH}	CLKBA or CLKAB	A or B	1.5	3.1	4	1	5	ns
t _{PHL}	CENDA OF CENAD	AOID	1.5	3.2	4.1	1	5	115
^t PLH	A or B	B or A	1	2.3	3.2	0.6	4	ns
tPHL	AOID	BUIA	1	3	4.1	0.6	4.9	115
tPLH	040 004	B or A	1	2.9	4.3	0.6	5.3	ns
tPHL	SAB or SBA†	BUIA	1	3.1	4.3	0.6	5.3	115
^t PZH	<u>OE</u>	A or B	1	3.4	4.6	0.6	5.9	20
tPZL	OE	AUID	1.5	3.5	5.3	1	6	ns
t _{PHZ}	<u> </u>	A or B	1.5	3.9	5.6	1	6.4	ns
t _{PLZ}	ŌĒ	AOIB	1.5	3.1	4.4	1	4.7	115
^t PZH	DIR	A or B	1	3.2	4.5	0.6	5.8	ns
tPZL	DIK	A UI B	1.5	3.4	5.1	1	6.7	115
^t PHZ	DIR	A or B	2	4.2	5.9	1.2	7.1	nc
^t PLZ	DIK	AUID	1.5	3.6	5.1	1	6.2	ns

These parameters are measured with the internal output state of the storage register opposite that of the bus input.

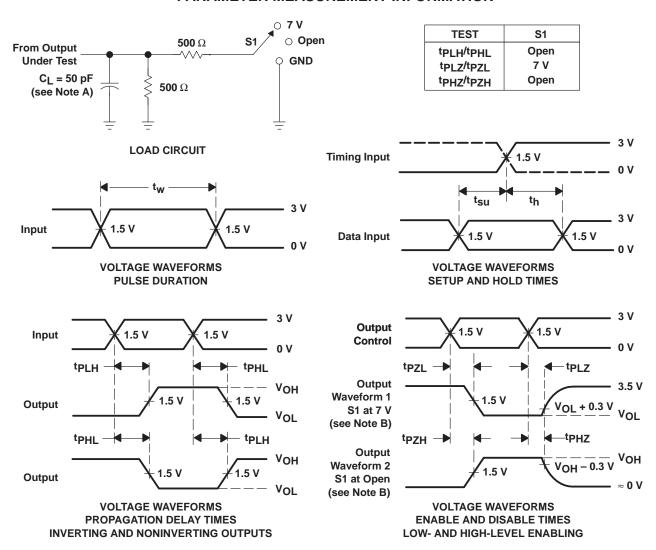
switching characteristics over recommended ranges of supply voltage and operating free-air temperature, $C_L = 50$ pF (unless otherwise noted) (see Figure 2)

				SN7	4ABT16	646		
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V ₍	CC = 5 V 4 = 25°C	!, ;	MIN	MAX	UNIT
			MIN	TYP	MAX			
f _{max}			125			125		MHz
^t PLH	CLKBA or CLKAB	A or B	1.5	3.1	4	1.5	4.9	ns
^t PHL	CLNDA OI CLNAD	AOIB	1.5	3.2	4.1	1.5	4.7	115
^t PLH	A or B	B or A	1	2.3	3.2	1	3.9	ns
^t PHL	AOIB	BUIA	1	3	4.1	1	4.6	115
^t PLH	SAB or SBA†	B or A	1	2.9	4.3	1	5	ns
^t PHL	SAB OI SBAT	DOIA	1	3.1	4.3	1	5	113
^t PZH	ŌĒ	A or B	1	3.4	4.6	1	5.5	ns
^t PZL	OE OE	AOIB	1.5	3.5	4.9	1.5	5.7	115
^t PHZ	ŌĒ	A or B	1.5	3.9	4.9	1.5	5.4	ns
t _{PLZ}	OE OE	AOIB	1.5	3.1	4.1	1.5	4.5	115
^t PZH	DIR	A or B	1	3.2	4.5	1	5.4	ns
^t PZL			1.5	3.4	4.8	1.5	5.6	115
^t PHZ	DIR	A or B	2	4.2	5.7	2	6.7	ns
t _{PLZ}		7016	1.5	3.6	5.1	1.5	5.9	115

[†] These parameters are measured with the internal output state of the storage register opposite that of the bus input.



PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50~\Omega,~t_f \leq 2.5~ns,~t_f \leq 2.5~ns$.
- D. The outputs are measured one at a time with one transition per measurement.

Figure 2. Load Circuit and Voltage Waveforms





PACKAGE OPTION ADDENDUM

10-Dec-2020

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
SN74ABT16646DGGR	ACTIVE	TSSOP	DGG	56	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ABT16646	Samples
SN74ABT16646DL	ACTIVE	SSOP	DL	56	20	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ABT16646	Samples
SN74ABT16646DLR	ACTIVE	SSOP	DL	56	1000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ABT16646	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

10-Dec-2020

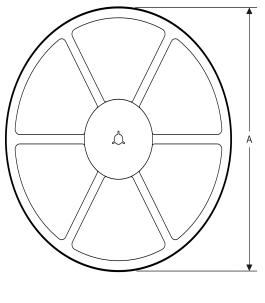
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

14-Jul-2012 www.ti.com

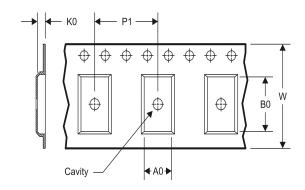
TAPE AND REEL INFORMATION

REEL DIMENSIONS





TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74ABT16646DGGR	TSSOP	DGG	56	2000	330.0	24.4	8.6	15.6	1.8	12.0	24.0	Q1
SN74ABT16646DLR	SSOP	DL	56	1000	330.0	32.4	11.35	18.67	3.1	16.0	32.0	Q1

PACKAGE MATERIALS INFORMATION

www.ti.com 14-Jul-2012



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74ABT16646DGGR	TSSOP	DGG	56	2000	367.0	367.0	45.0
SN74ABT16646DLR	SSOP	DL	56	1000	367.0	367.0	55.0

DL (R-PDSO-G56)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MO-118

PowerPAD is a trademark of Texas Instruments.





SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
 4. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



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